

SOTERIA MIDTERM WORKSHOP

IMPROVEMENT OF THE PHYSICALLY-BASED CONSTITUTIVE STRESS-STRAIN EQUATIONS AND THE POST-IRRADIATION FRACTURE RESPONSE OF RPV STEELS

10TH APRIL 2018

Contribution to SOTERIA WP5

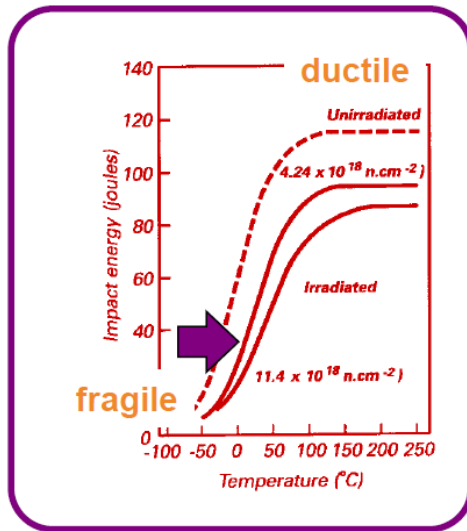
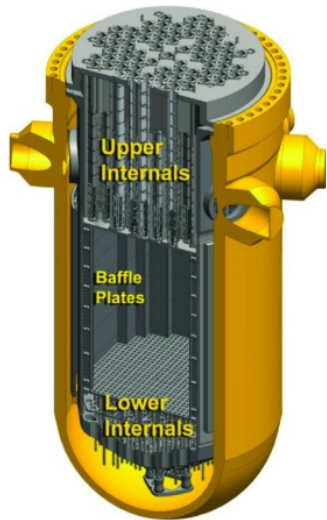
Co-workers: B. Marini, P. Forget, K. Singh, L. Vincent, Y. Li

Speaker: **Christian Robertson**

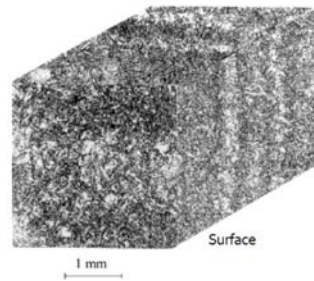
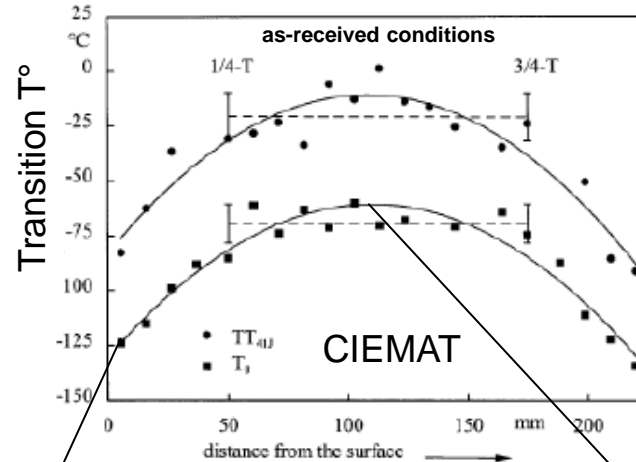
Long-term goal or vision: predicting dose-dependent fracture toughness response based on non-destructive post-irradiation examinations (material polycrystalline microstructures, i.e. grain sizes and orientations; irradiation defect microstructures) and physically based models

☞ minimizing/optimizing time-consuming/costly mechanical testing of post-irradiated specimens in hot cells

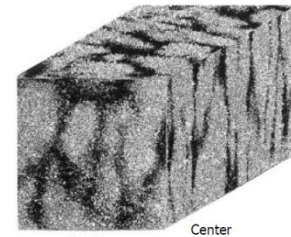
Thick-walled components: microstructure and fracture toughness variability



Microstructural variations = one possible contribution...



outer surface



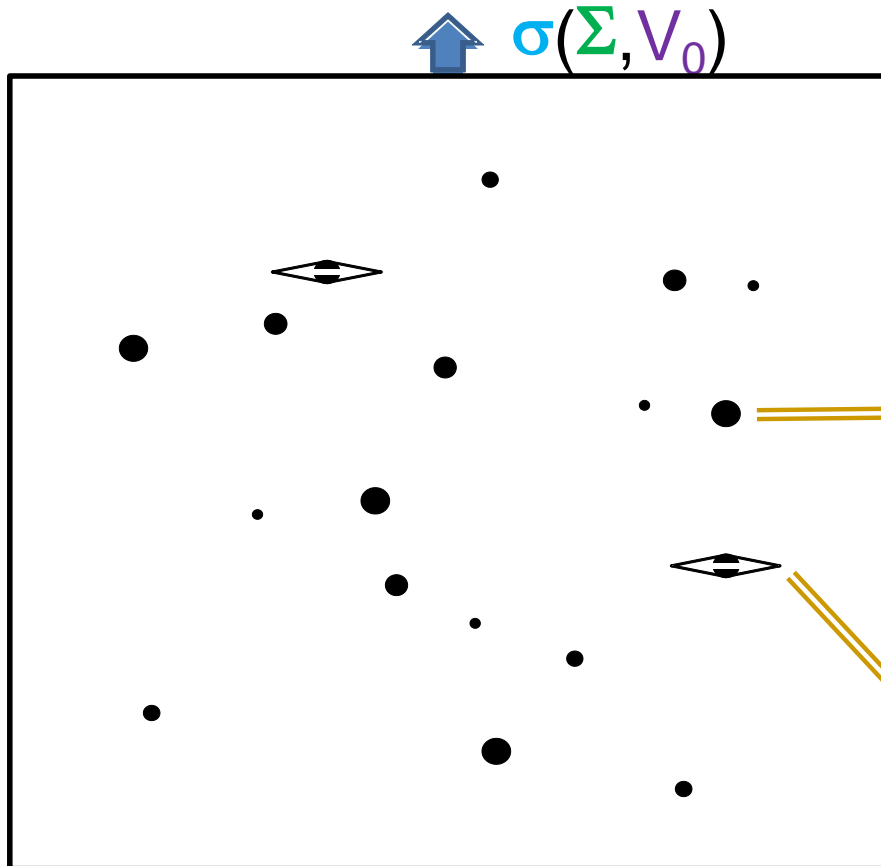
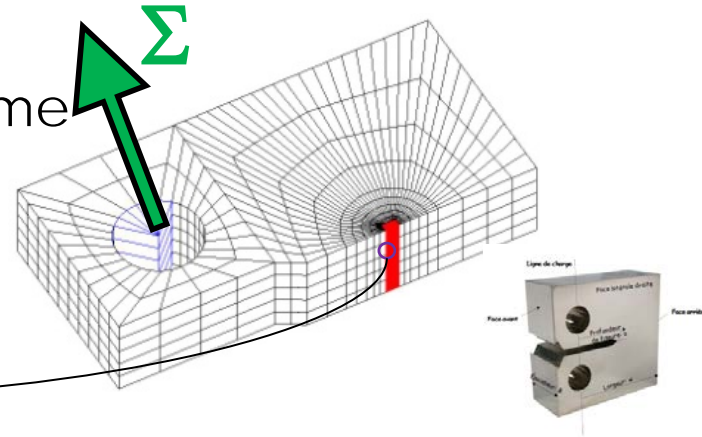
center

B. Marini, Lecture series

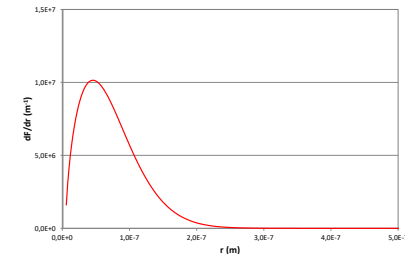
👉 Modelling efforts addressing: dose-dependent fracture response and its scattering

«Local approach of fracture models»

- Σ : specimen-scale loading level
- V_0 : representative elementary volume
- σ : stress level acting on V_0



- Particle size distribution: $f(r) = dF/dr$



- Griffith fracture propagation criteria :

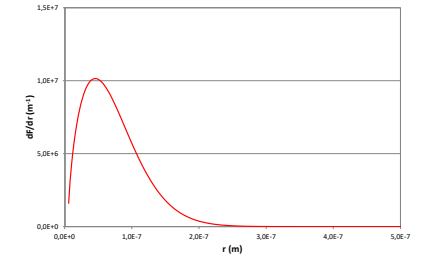
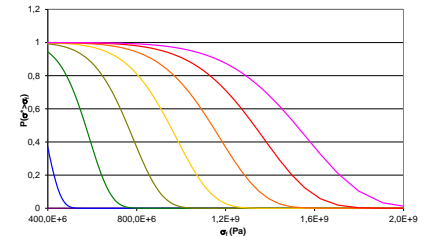
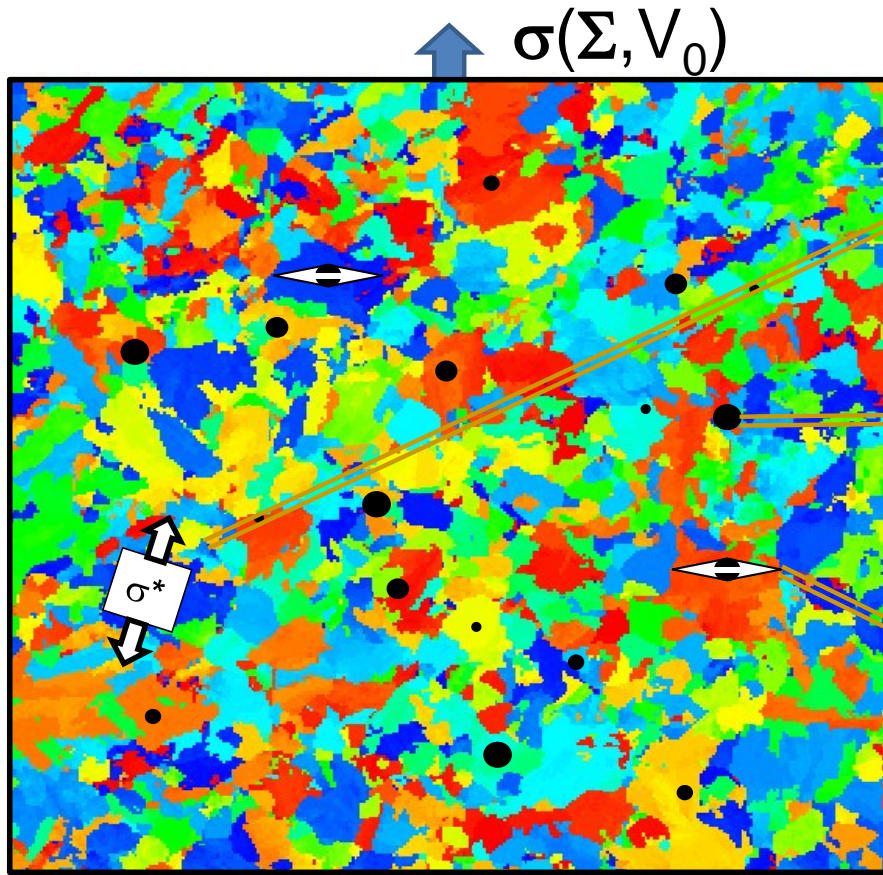
$$\sigma_c = \sqrt{\frac{\pi}{2(1-\nu^2)} \cdot \frac{E \cdot \gamma_f}{r}}$$

...including local stress distribution (MIBF)

➤ **MIBF model INPUTS** : irradiation-induced hardening level, particle size distribution, surface energy, grain-size, grain orientation, grain-scale stress fields

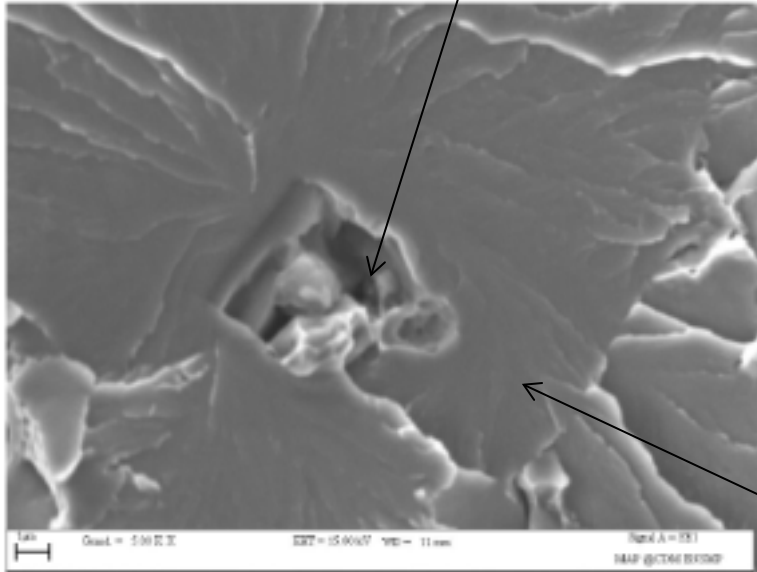
J. Nucl. Mat. 406 (2010) 91-96

RPV steel microstructure
 ⇒ local stress distribution σ^* inside V_0 .



$$\sigma_c = \sqrt{\frac{\pi}{2(1-\nu^2)} \cdot \frac{E \cdot \gamma_f}{r}}$$

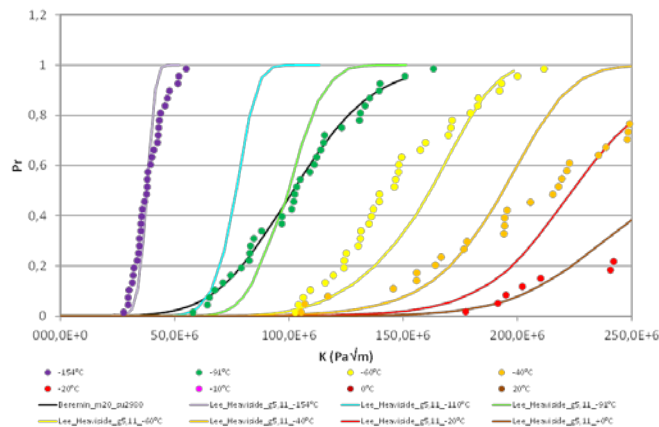
Cracked inclusion: brittle fracture initiator



Weakest link assumption

- I- all inclusions/particles break down, for $\epsilon > \epsilon_{p0}$
- II- micro-cracks grow (or not) according to a definite criteria
- III- first micro-crack develops → the whole specimen fails
- IV- **fracture toughness then directly relates to plastic zone size a_0 , near the micro-crack initiators**

Cleavage fracture surface

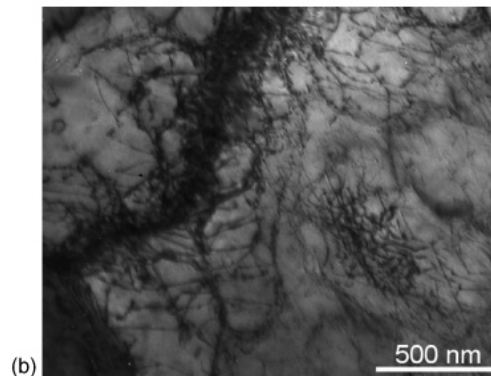
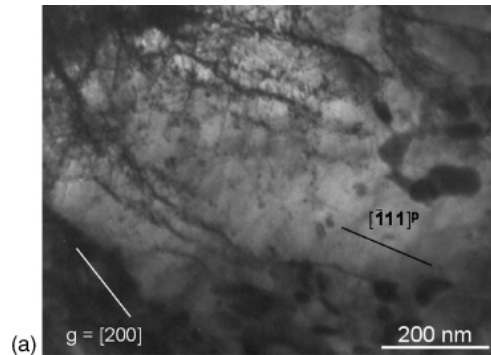


Transition curves, DBT shift

Micro-crack induced plastic zone?

- Q. Effect of straining temperature on a_0 ?
- Q. Grain size and orientation effect on a_0 ?
- Q. Dose effect, irradiation temperature effect, on a_0 ?

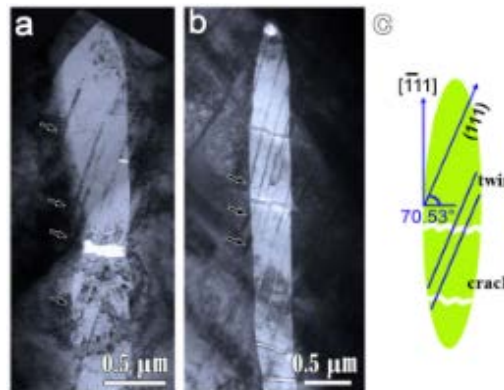
R. Crack-induced plasticity: dislocation-mediated



Modelling Simul. Mater. Sci. Eng. **18** (2010) 025003

☞ «Statistical, investigation of post-irradiation plasticity mechanisms using, 3D DD simulations»

☞ Dislocation Dynamics simulations?



MnS in steel, Sci. Reports 4, 5118 (2014)

Dislocation dynamics simulations?



« TRIDIS » code

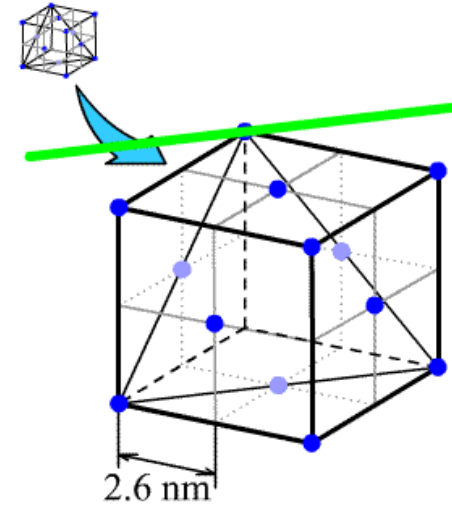
Model. Simul. Mater. Sci. Eng. 6 (1998) 755-770

Dislocation Model

Discrete dislocation lines

Discrete time steps: 10^{-10} s

Discrete bcc lattice



Stress

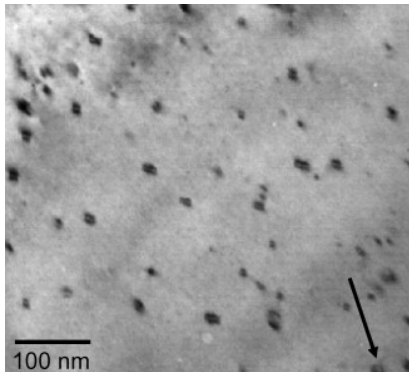
Dislocation Dynamics
code

Dislocation microstructures

Plastic strain

Dislocation theory

- Dislocation mobility (stress and T° dependent)
- Interaction with radiation defects, other dislocations, GB...
- Cross-slip



FCC models (Cu, FCC Fe)

Screw ~ Edge

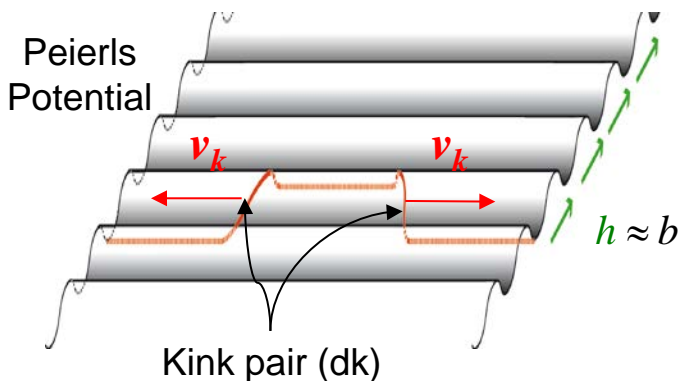
Negligible Peierls barrier ($\tau_p \sim 10$ MPa)



Phonon-drag mechanism

$$v_{screw}(\tau) = v_{edge}(\tau) = \frac{\tau b}{B}$$

- τ : applied stress $\gg \tau_p$
- B : Viscous drag coefficient
- b : Burgers vector module
- τ_p : Peierls Stress



BCC Fe and Fe alloys

Screw \neq Edge

Velocity anisotropy depends on T°

Low temperature

High temperature

Significant Peierls barrier ($\tau_p \sim 1$ GPa)



Thermally activated mobility

$$v_{screw}(\tau, T) \ll v_{edge}(\tau) = \frac{\tau b}{B}$$

Athermal regime

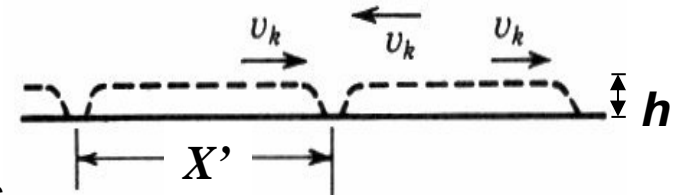
$$v_{screw} \approx v_{edge}$$

Low-T screw dislocation mobility mechanism

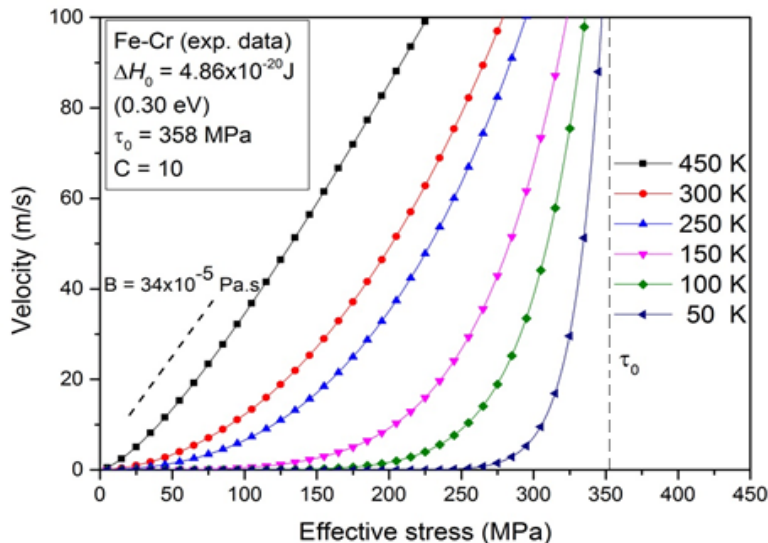
- **Nucleation** of a kink pairs (thermally activated)
- Kink pair **propagation** $v_k \propto \tau$ « effective » $B_k < B_{edge}$

Journal of Nuclear Materials 504 (2018) 84-93

$$v_{screw} = hJX'$$



- h : distance between Peierls valleys
- J [$\text{m}^{-1}\text{s}^{-1}$] : kink pair **nucleation rate** per unit length
- X' [m] : kp **mean free path** before annihilation with another dk
[increases with kink velocity (v_k) and decreases with J]



$$v_{screw}(\tau^*, T) = \underbrace{\frac{8\pi b(\tau^*)^2}{\mu B h}}_{\text{Stress-dependent pre-factor}} X' \exp\left(-\frac{\Delta G(\tau^*, T)}{k_B T}\right)$$

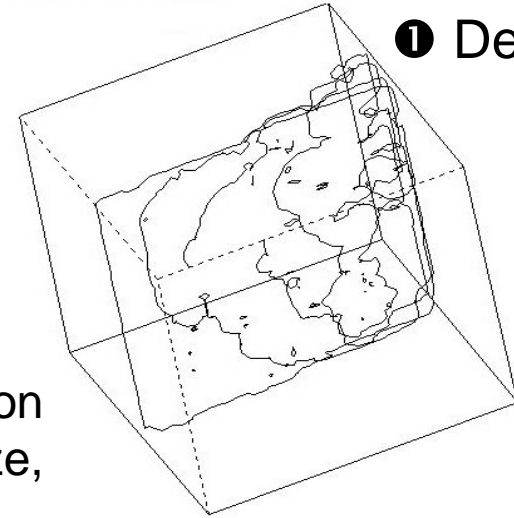
Stress-dependent pre-factor

☞ Progressive transition from Low- T to Room- T

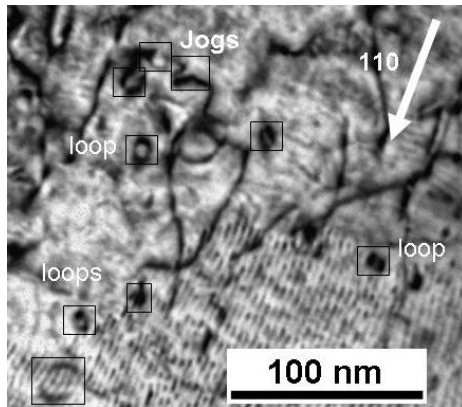
1 μm^3 ferritic grains (Fe-C or Fe-Cr):

- Defect number density and defect size depend on selected dose and T_{irr} condition
- Uni-axial tension, strain-rate controlled conditions, fixed straining T° , presence of cross-slip
- **Model INPUTS** : grain size, kink-pair activation energy, phonon drag coefficient, irradiation defect size, and number density

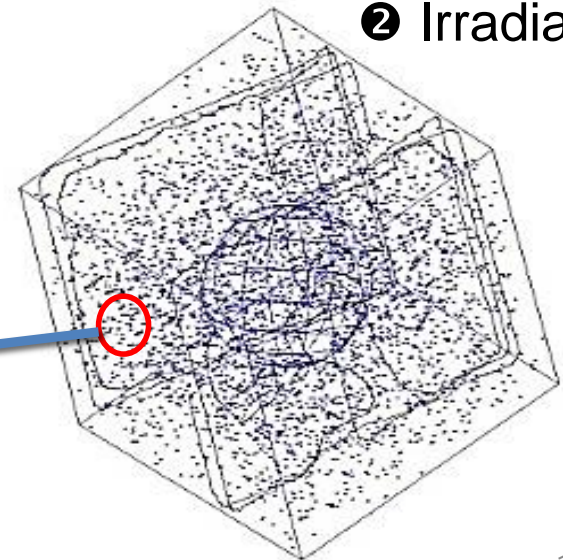
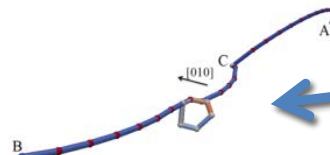
① Defect-free



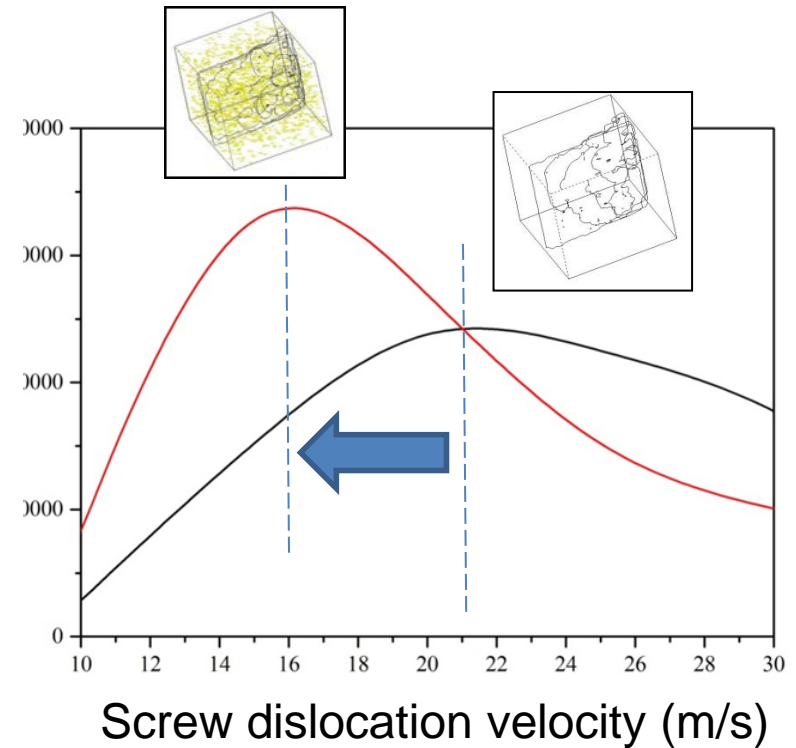
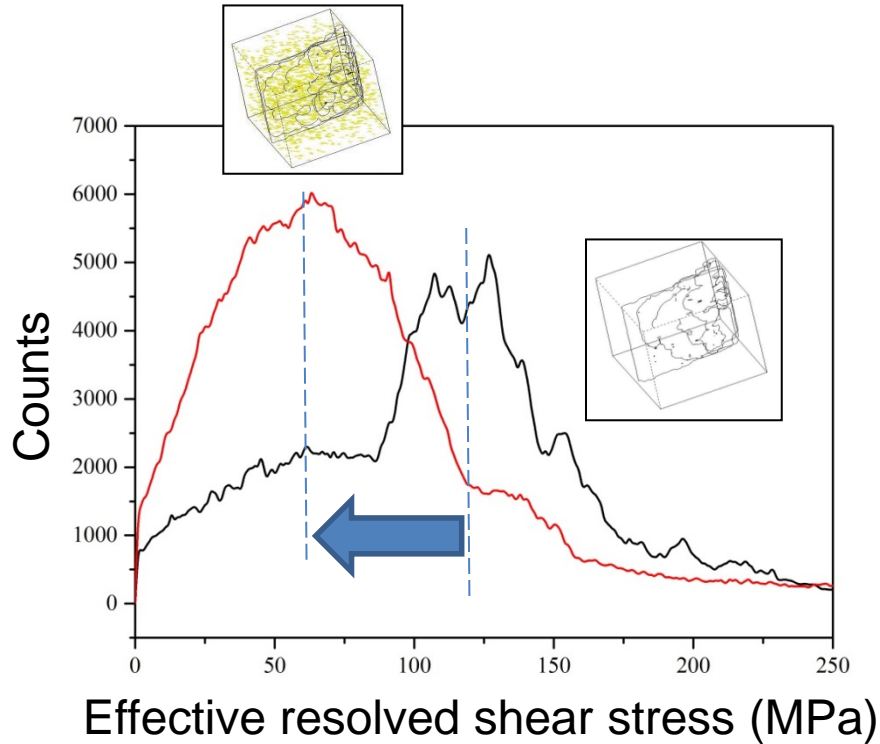
② Irradiated



dislocation/defect interactions

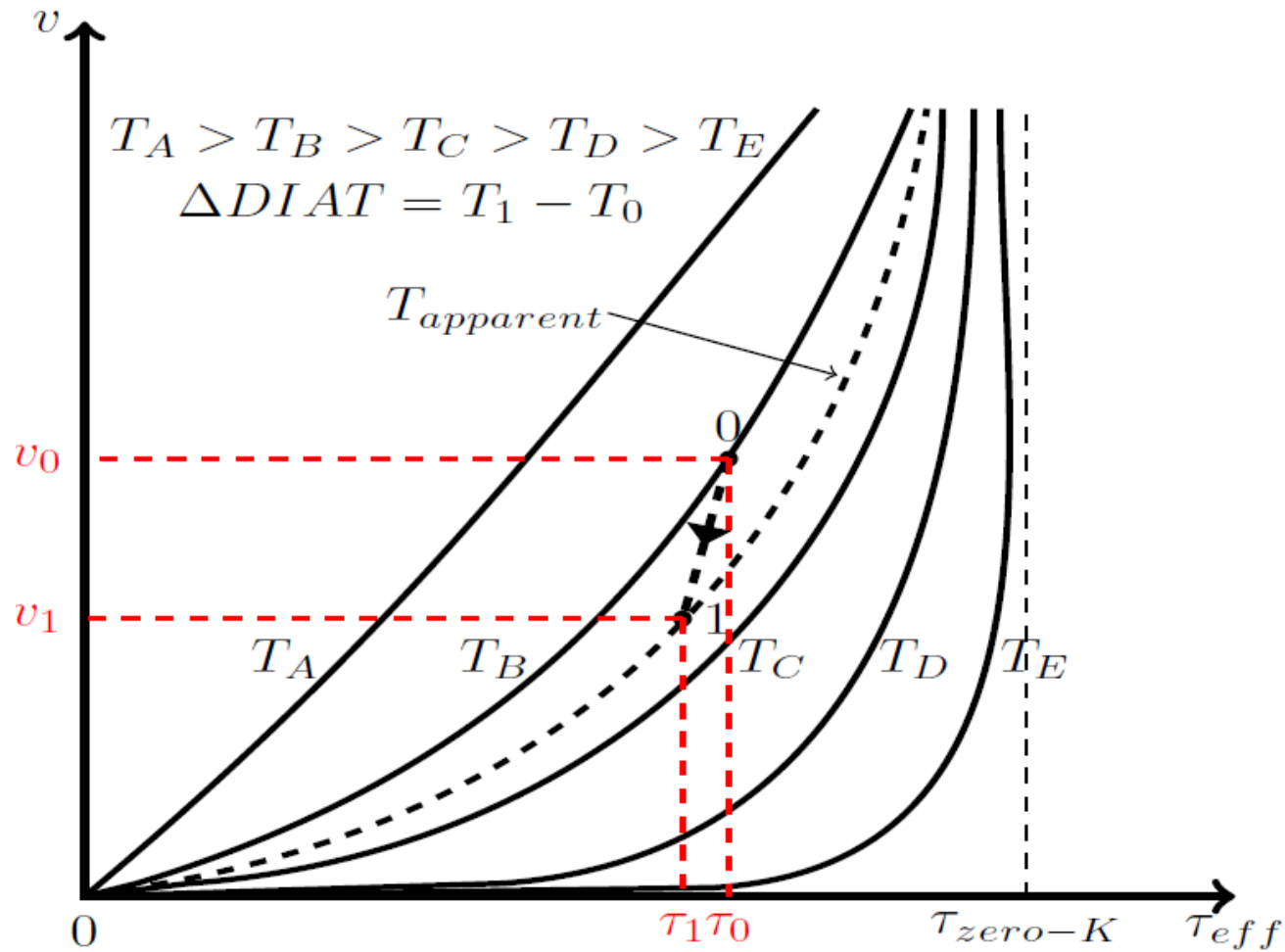


$T_{irr}=400^\circ\text{C}$, dose = 1 dpa, defect size $D = 50 \text{ nm}$



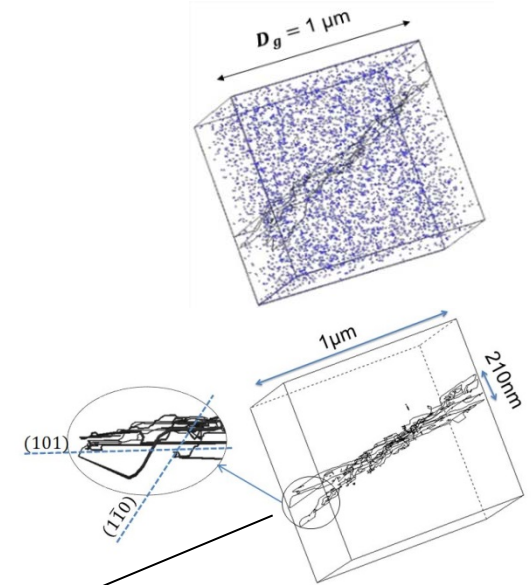
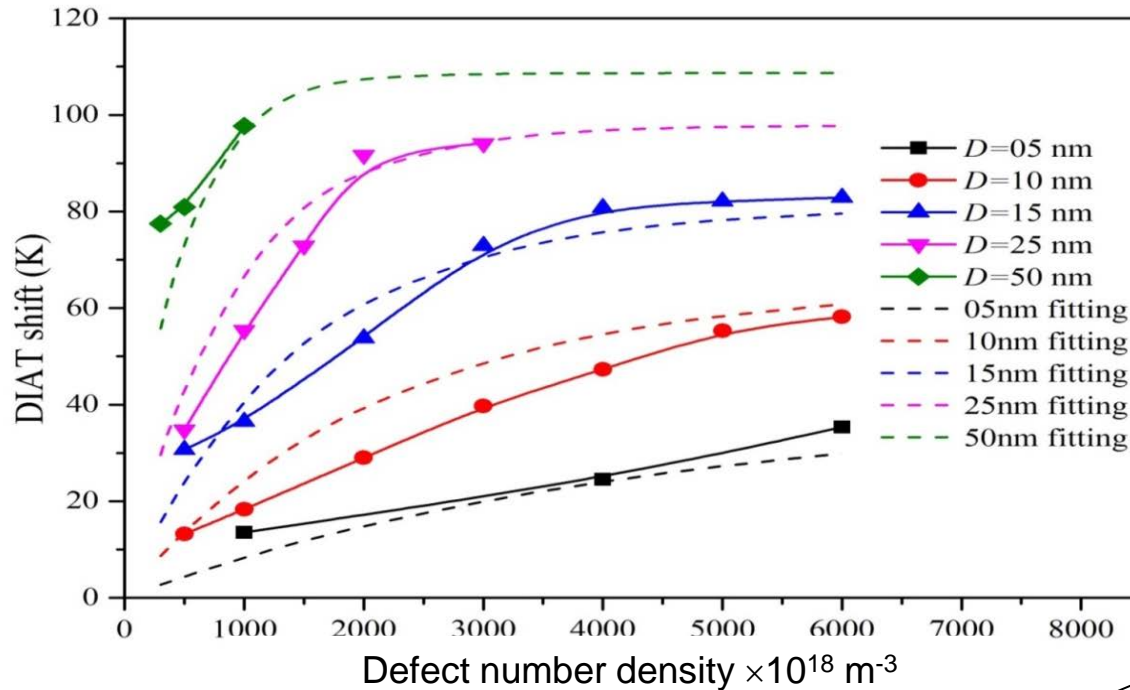
- Defect-induced effect on effective screw dislocation mobility : **statistically significant**

DIAT shift: interpretation

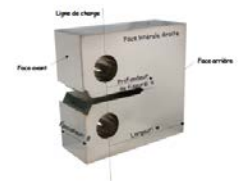


$T_{apparent} - T_0 =$ Defect-Induced Apparent straining Temperature shift ($\Delta DIAT$)

Δ DIAT: a systematical investigation



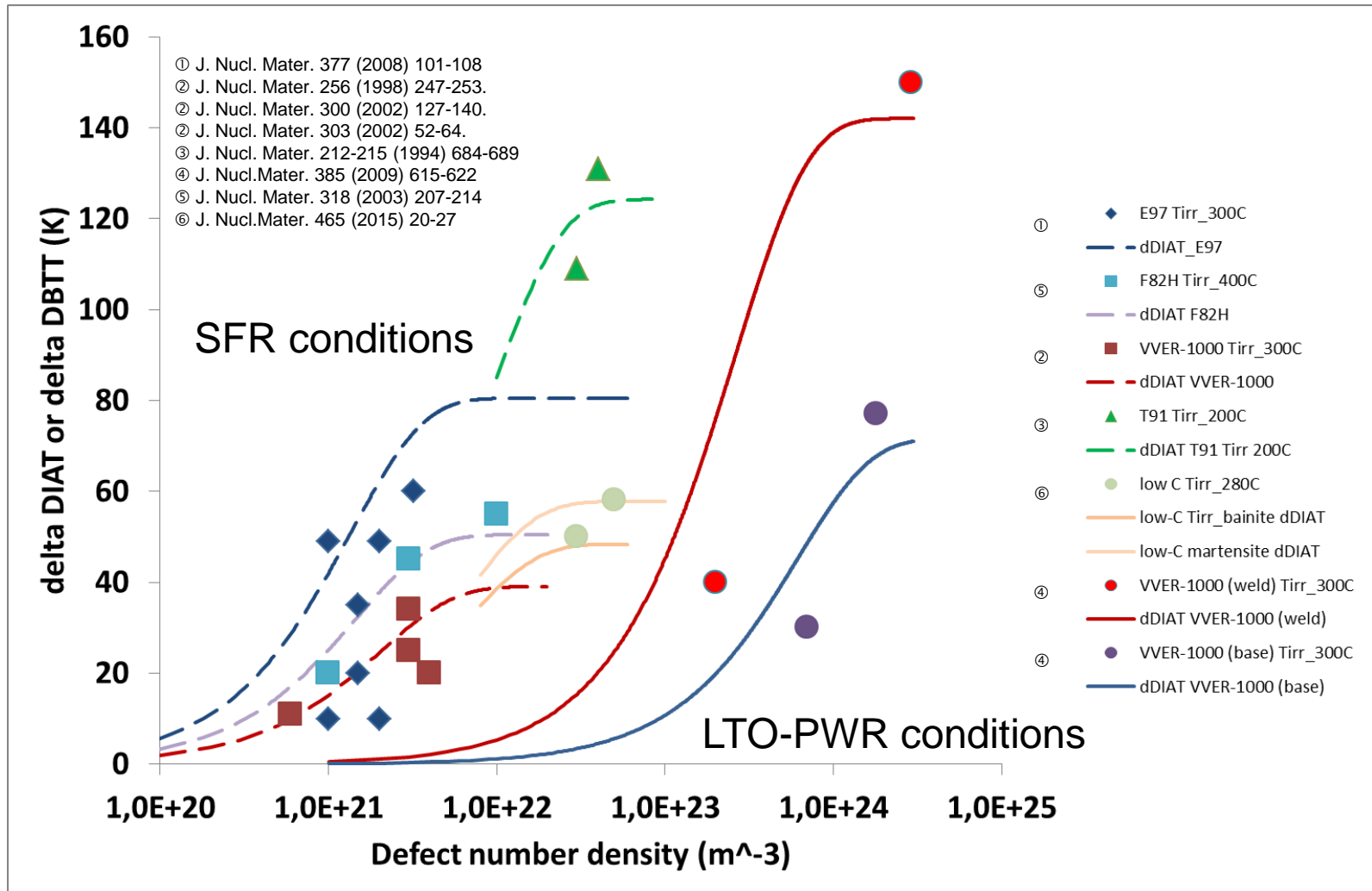
$$\Delta \text{DIAT} = \Delta T_{max} \left(1 - \exp\left(-\frac{D}{\lambda}\right) \right) \left(1 - \exp(-d^2 DN) \right) \approx \Delta T_0 / \Delta \text{DBTT}$$



N : defect number density (in nm^{-3}); D : defect size (in nm);
and **3 material-dependent scaling parameters** (ΔT_{max} , d and λ)

This description potentially includes segregation effects at dislocation sources (augmenting ΔT_{max}) and GB (decreasing critical stress-localisation threshold \rightarrow shear band thickness d and mean free path λ)

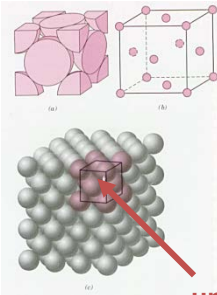
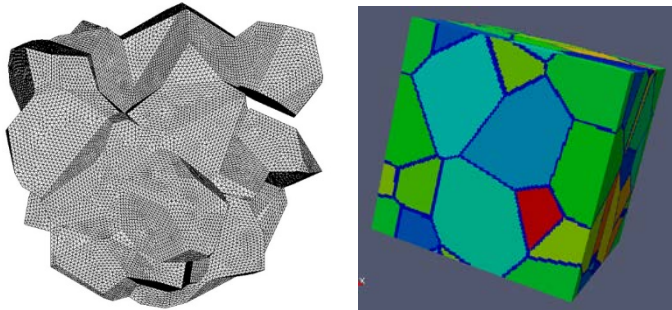
Δ DIAT/ Δ DBTT comparison



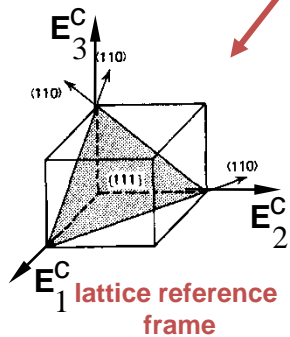
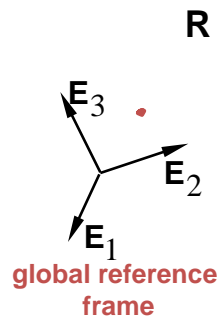
Δ DIAT \approx Δ DBTT [irradiation conditions: little or no segregation at fracture initiators (particles or GB)]

Absolute toughness levels: link with local approach of fracture/MIBF approach/models

Support/link dose-dependent crystal plasticity...



unit cell



FCC
12 slip systems
 $m=\{111\}, s=\langle 110 \rangle$

BCC
12 slip systems
 $m=\{110\}, s=\langle 111 \rangle$

- Explicitly models discrete grains and slip systems, accounting for anisotropy of single crystal properties and crystallographic texture.
- Slip system level constitutive equations for dislocations with use of Internal state variables for various parameters at each slip system
- Approach used to study aggregate of crystals to obtain a better understanding of single-crystal or polycrystal behavior.

Support from DD-based simulations

- Physically based stress-velocity rules, system-system interaction strength
- Evolution of irradiation defect population with increasing strain, mobile dislocation density evolution

Modified T° -dependent mobility rule



$$\frac{1}{\dot{\gamma}_{total}} = \frac{1}{\dot{\gamma}_{nuc}} + \frac{1}{\dot{\gamma}_{prop}}$$

$$\dot{\gamma}_{nuc} = \rho_{mob} b \frac{8\pi\tau_{eff}^2}{\mu B} \exp\left[-\frac{\Delta H_0}{k_B T} \left(1 - \left[\frac{\tau_{eff}}{\tau_0}\right]^p\right)^q\right] l_s \quad (1)$$

$\dot{\gamma}_{nuc}$ accounts for thermally activated kink pair nucleation.

The stress-independent l_s term assumes that each nucleated kink-pair sweeps the whole dislocation line, while a given screw dislocation moves from one Peierls valley to the next one.

Inverse of strain rate sensitivity parameter

Reference shear strain rate

$$\dot{\gamma}_{prop1} = \dot{\gamma}_0 \left(\frac{\tau_{RSS}}{\tau_c}\right)^n$$

$$\dot{\gamma}_{total} \propto \frac{l_s X_\infty}{l_s + X_\infty}$$

Requirement of very high value of $n = 100$ limits its numerical implementation. Generally lower values of $n=50$ is used to avoid numerical issues.

Use of lower value of n leads to inaccurate coupling between the rate sensitive macroscopic response and rate sensitive evolution of critical shear stress.

$$\dot{\gamma}_{prop2} = \rho_{mob} b \frac{8\pi\tau_{eff}^2}{\mu B} \exp\left[-\frac{\Delta H_0}{k_B T} \left(1 - \left[\frac{\tau_{eff}}{\tau_0}\right]^p\right)^q\right] X_\infty \quad (2)$$

$$X_\infty = 2\sqrt{\frac{v_k}{J}}$$

Formulations (1)&(2) yield comparable results at the strain rate 10^{-4} for $\Delta H_0 > 0.6$ eV.

However, formulation (2) is able to handle a **larger range of strain rate and material parameters**. It is also found to be more robust in terms of convergence in finite element formulation.

- Irradiation defects (assumed to be uniformly distributed) are accounted as obstacles cutting the dislocation glide planes hence treated as forest obstacles to the glide of dislocations.

$$\alpha^A = \sqrt{\sum \alpha^{AF} \frac{\rho^F}{\rho_{obs}^A}}$$

- Irradiation defects with their density $\rho_{irr} = N_{irr} d_{irr}$ and respective strength interacts with dislocations.
- Dose level controls the number of loops formed and temperature controls the size of the loop.

Irradiation defect density evolution

$$\dot{\rho}_{irr} = -\xi \rho_{irr} \dot{\gamma}$$

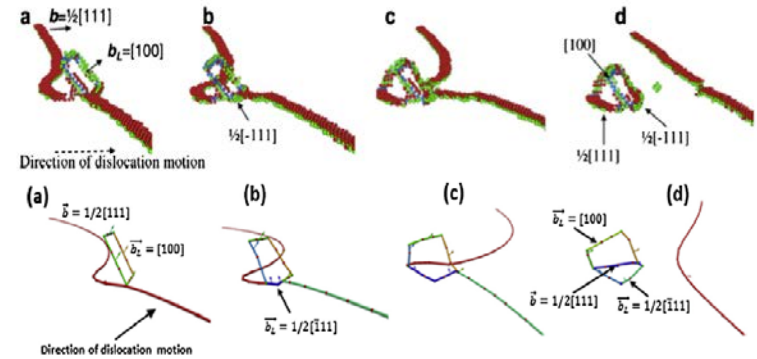
Affects τ_{eff} in eq. (2)

ξ : loop annihilation parameter

This term is defect number density dependent (irradiation dose)

Through DD simulations → significant dose-dependent increase in total and mobile dislocation density.

This increase is ascribed to interaction of screw dislocations with irradiation defects → dislocation pinning, multiplication.



X.J. Shi et al. *J. Nucl. Mat.* 460 (2015) 37-43

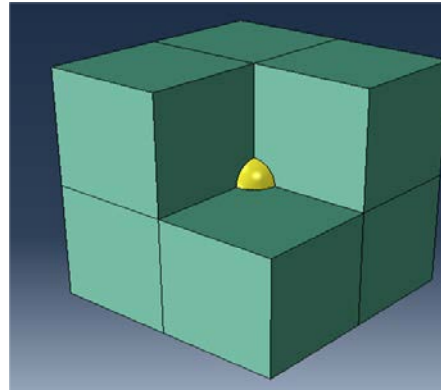
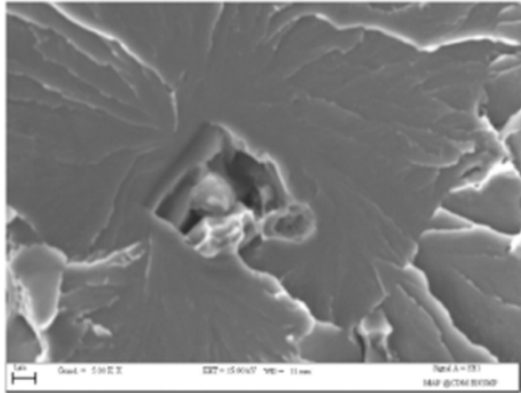
$$\dot{\rho}_m = \frac{\kappa \xi}{r_0} \rho_{irr}(t) \dot{\gamma}$$

affects $\dot{\gamma}$ in eq. (2)

☞ Interaction means dislocation pinning, which subsequently act as source of mobile dislocation for their further generation.

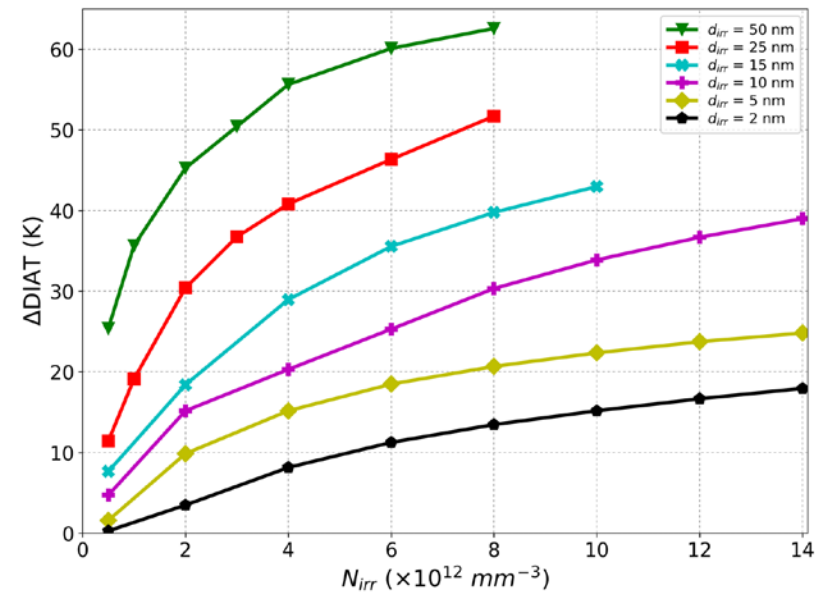
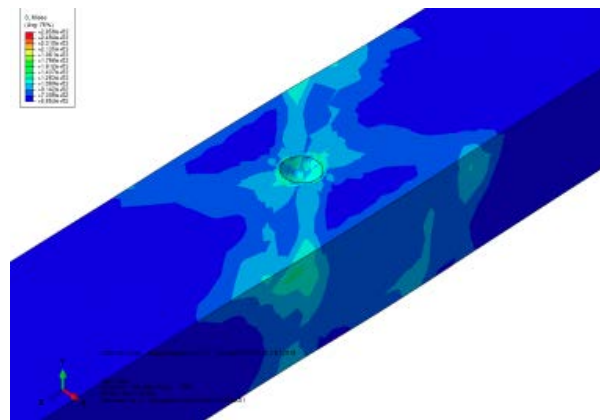
☞ This mechanism/term is defect-size dependent (irradiation temperature)

Preliminary results: FEM model



To predict stress field near fracture initiator and its dose-dependent evolutions

- ☞ Link with DD calculations: Δ DIAT prediction
- ☞ Link with MIBF model

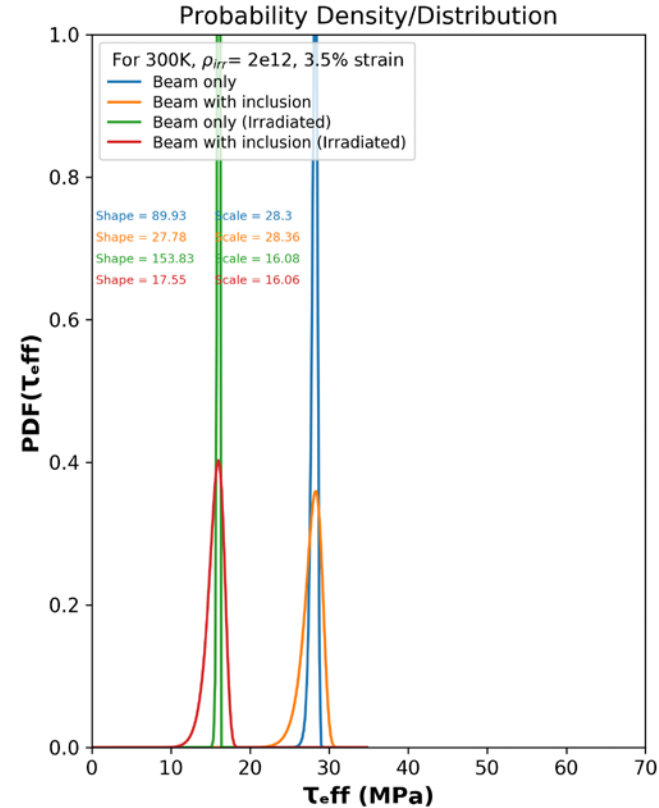
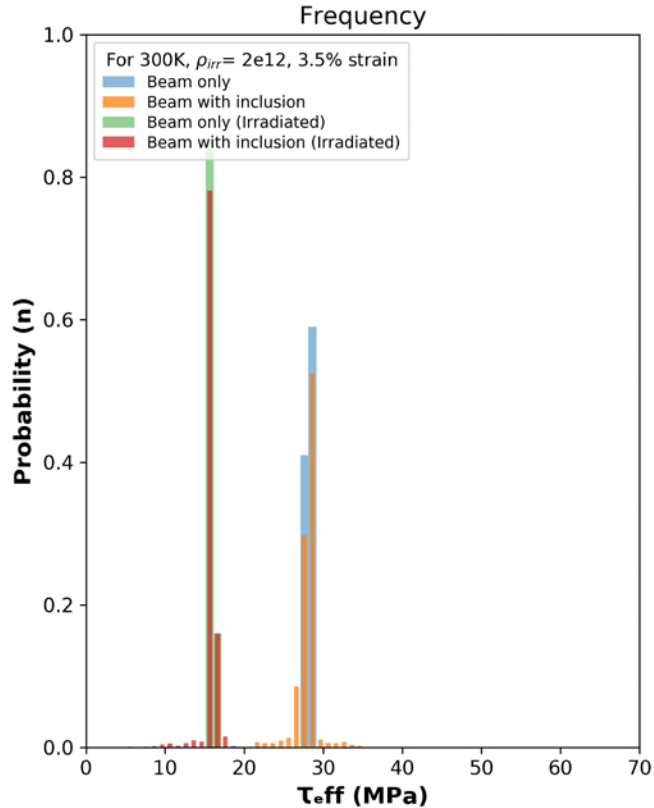


Stress field near fracture initiator:
Weibull statistics description

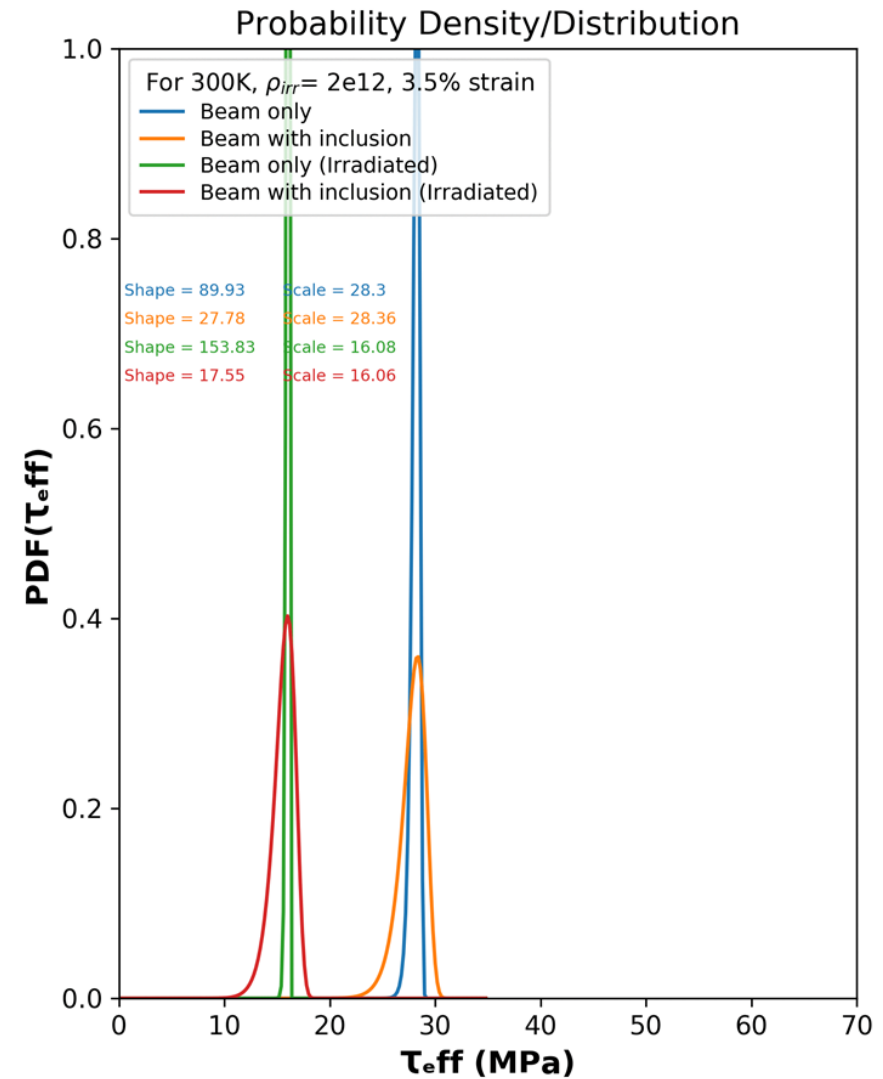
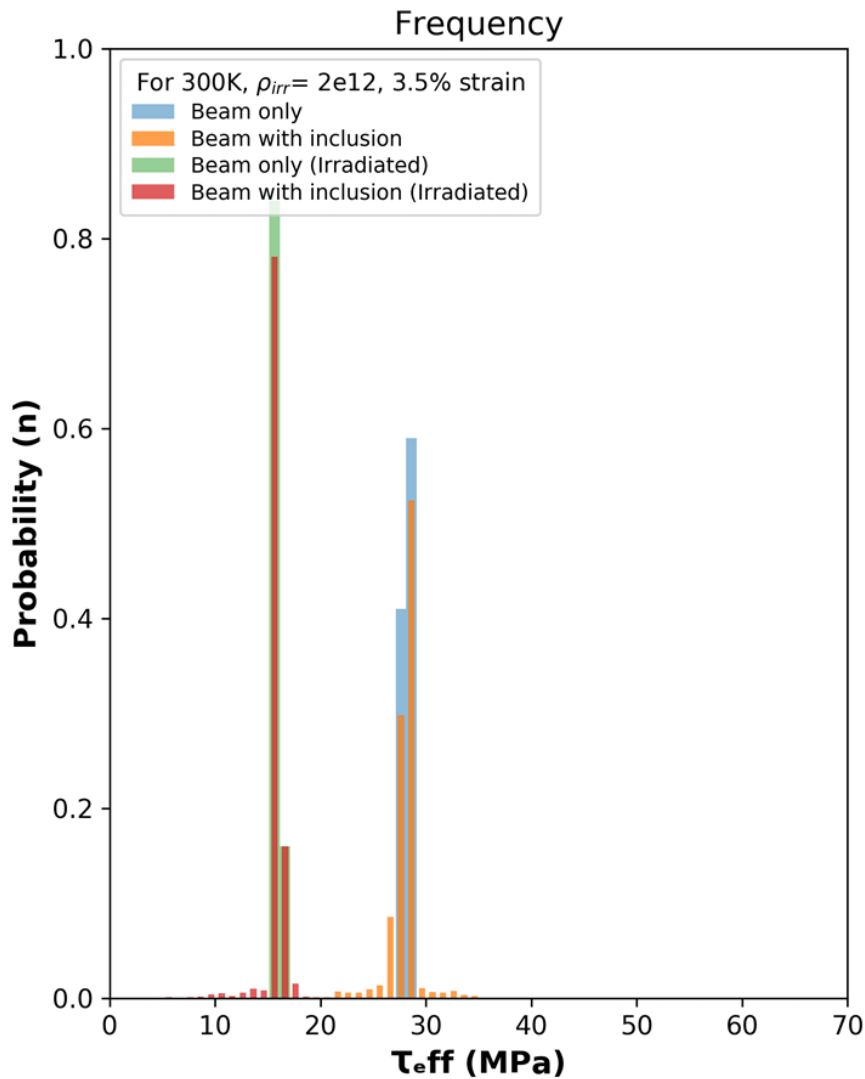
$$f(\tau_{eff}) = \frac{\beta}{\eta} \left(\frac{\tau_{eff} - \gamma}{\eta} \right)^{\beta-1} \exp - \left(\frac{\tau_{eff} - \gamma}{\eta} \right)^{\beta}$$

Scale Parameter \leftarrow η \leftarrow Position Parameter

Shape Parameter \leftarrow β



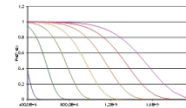
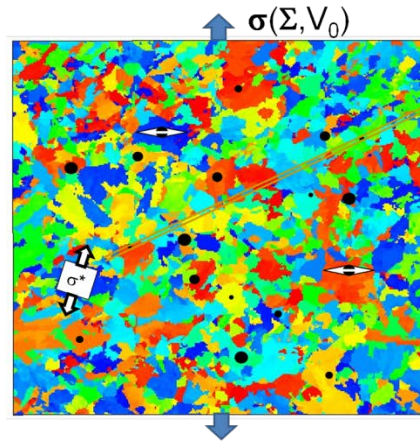
Irradiation defect size - 15 nm



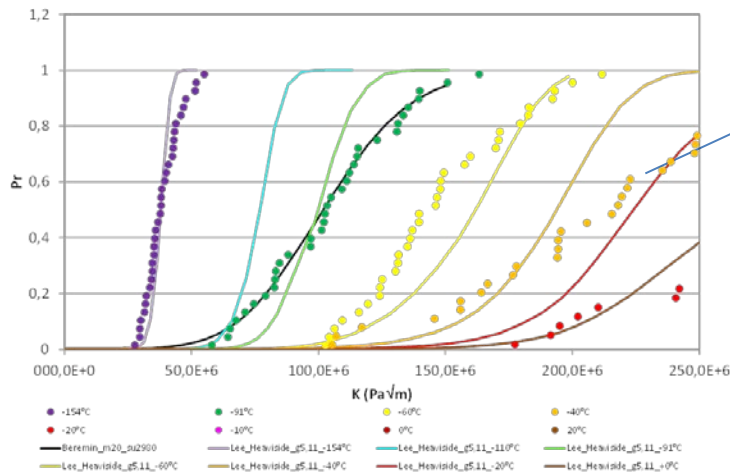
Preliminary results: link with MIBF model

Ongoing: to compare Δ DIAT and Δ DBTT based on MIBF prediction

RPV steel microstructure
 \Rightarrow local stress distribution σ^* inside V_0 .



$+\Delta\sigma$ or dose-dependent change of Weibull grain stress distribution parameters



$$P_f(V_p, \Sigma) = 1 - \exp \left(\int_{V_p} \ln(1 - P_f(V_0, \sigma)) \frac{dV}{V_0} \right)$$

Example: as-received (0 dpa) conditions
 Solid line: without grain plasticity
 Solid symbols: accounting for grain plasticity

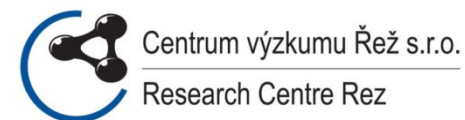
In presence of disperse defect populations:

- Weakest link fracture framework: toughness level is controlled by the **plastic zone size « a_0 »**, off the BF initiators (particles or GB)
- Plastic zone size « a_0 » is **dose-dependent** and scales with the **apparent (screw) dislocation mobility**
- Apparent dislocation mobility depends on dispersed defect populations and can be estimated using the **statistical Δ DIAT concept**
- Calculated Δ DIAT levels are comparable to DBT transition shifts, for a given disperse defect microstructure (N , D)
- DD and Δ DIAT approach used in support of crystal plasticity calculation framework
- Corresponding dose-dependent stress distributions to feed MIBF model, predicting DBT level and shift

Perspectives:

- To apply Δ DIAT method to a broader range of materials and irradiation conditions
- To predict dose-dependent evolutions of upper shelf level

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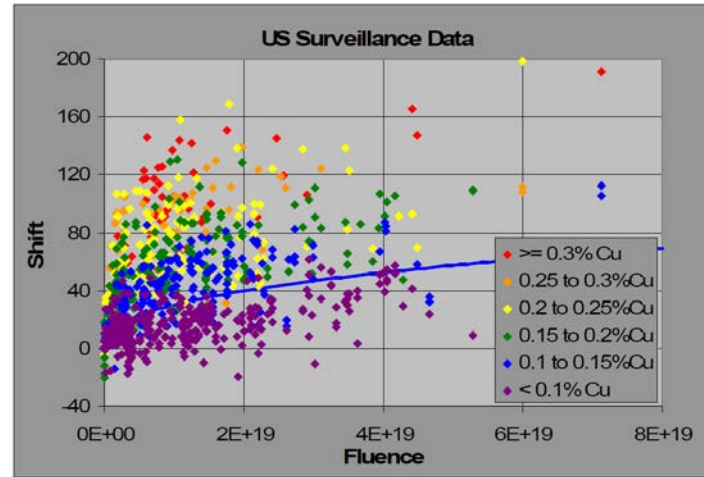
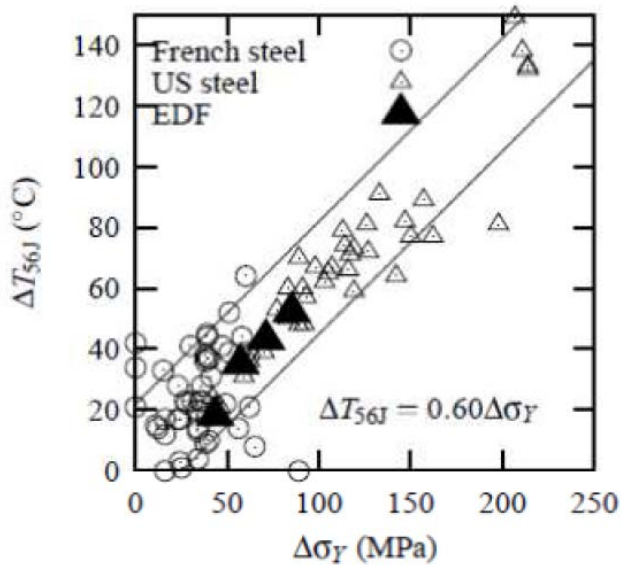
The SOTERIA Project Office

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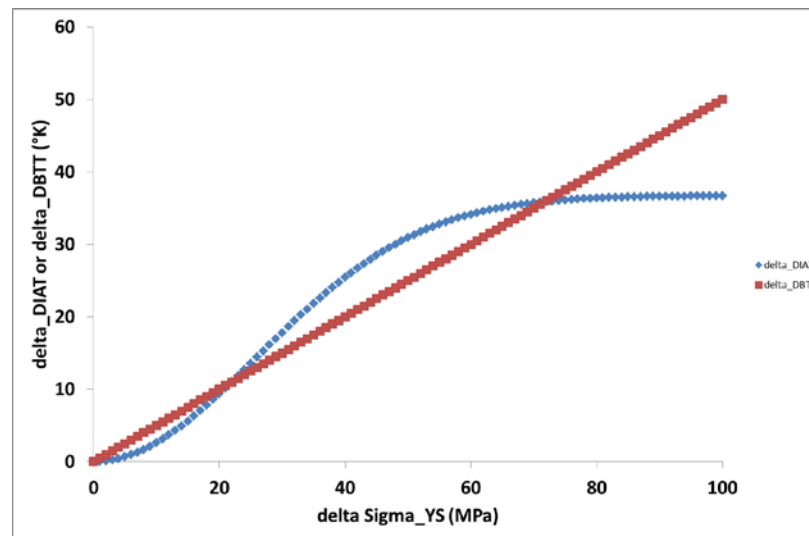
www.soteria-project.eu

This project received funding under the Euratom
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under grant agreement N° 661913.

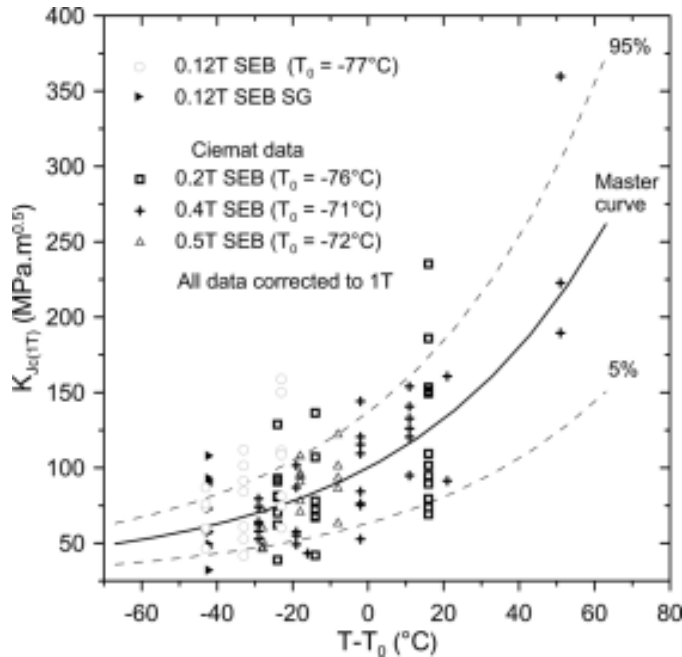




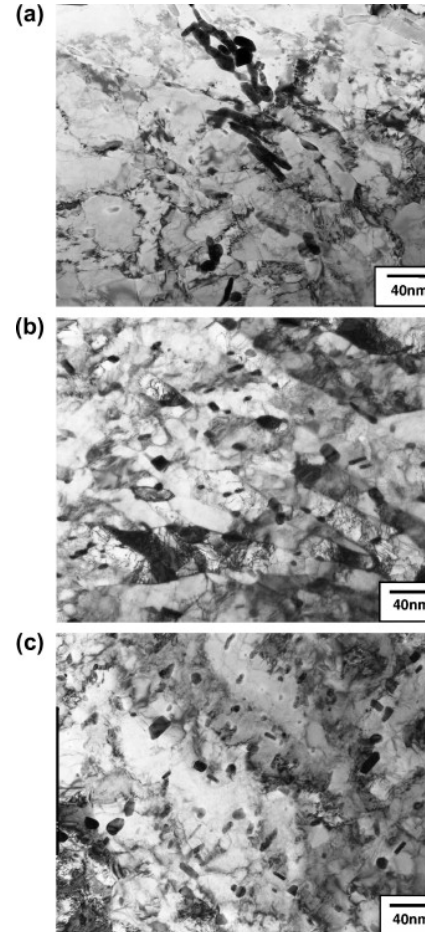
Williams, 2005 (ISQUID)



RPV steel fracture toughness evolution



J. Pressure Vessel Technol 139(4), 041410 (2017)



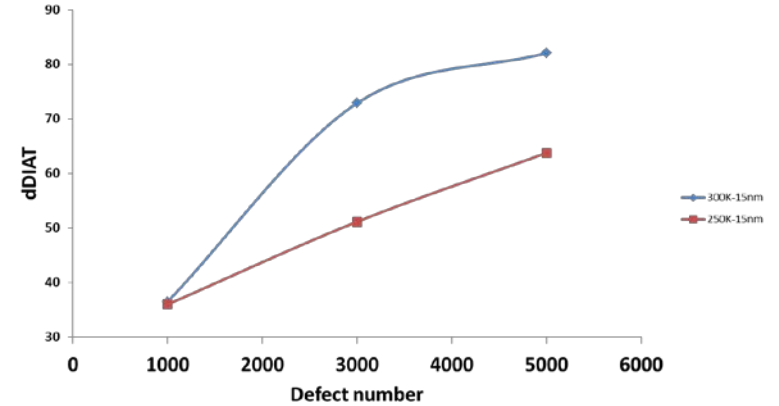
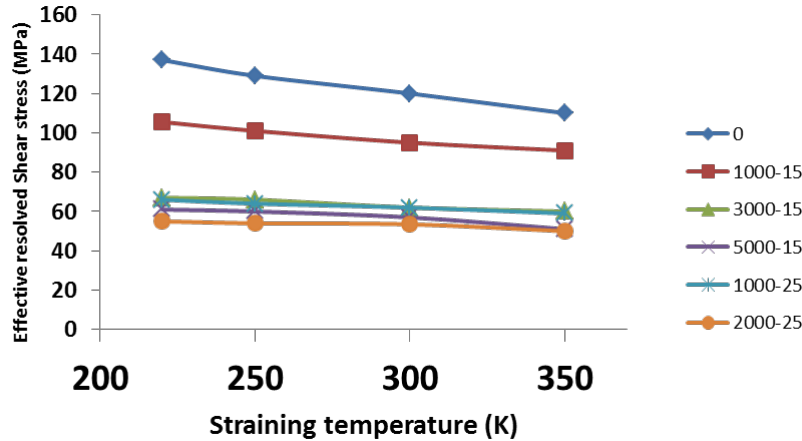
Low-C
ferritic
RPV steel

JNM, 407, 2010, Pages 126-135

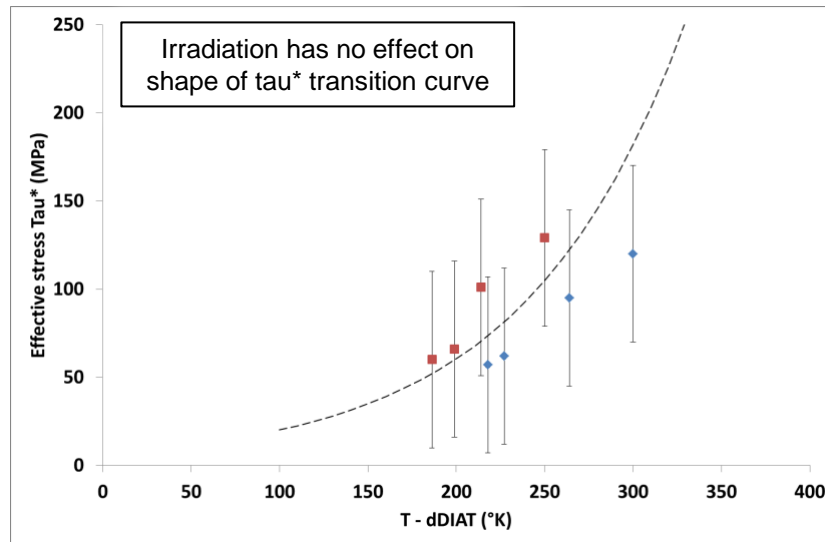
- ☞ Populations of inclusions/particles
- ☞ Sub-grain laths and lath-blocks



Discussion: Δ DIAT concept validation



Dose-independent «Master curve»: τ^*



Dose-independent Master curve: K_0

